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Shifts:	Local contact(s): Virginia Monteseguro padron	Received at ESRF:
15	(email: monteseguro.virginia@esrf.fr)	
Names and affiliations of experimentalists (* indicates applicants):		
*Dr. Boby Joseph, Elettra-Sincrotrone Trieste (<u>boby.joseph@gmail.com</u>),		
*Prof. Giovanni Hearne (grhearne@uj.ac.za), Dr. S. Bhattacharjee, Prof. E. Carleschi,		
Dept. Physics, University of Johannesburg, South Africa		

Report:

In semiconducting intermetallic FeGa₃, our high pressure x-ray diffraction studies showed that the 15–20 GPa initiate a disruption of the tetragonal P4₂/mnm structure. Around the same pressure there is an emergence of a high-pressure metallic phase. Ga K-edge XANES and EXAFS measurements carried out provided important information.

Up to ~19 GPa there is a continuous evolution of Ga K-edge near-edge (XANES) features. This is followed by a distinct change where a second group of XANES profiles could be distinguished (see Fig. 3 (a) of the below cited publication). Compared with the LP suite, HP XANES profiles at P > 19 GPa are characterized by a clear shift in edge position, reduction in intensity, and broadening of the main absorption feature at ~10370 eV.

Extended absorption fine structure (EXAFS) beyond 19 GPa also demonstrated stark changes occurring beyond 19 GPa. Above 19 GPa, there is a pronounced damping of the oscillation amplitudes. A comparison of the Fourier-transform magnitudes $FT|k2\chi(k)|$ of representative LP and HP EXAFS clearly evidenced changes in the first-shell region R ~ 2 Å, suggestive of distinct Ga local environments for LP and HP phases.

Main results from the present study are recently published as a rapid communication in Phys. Rev. B. Details of the publication are given below.

Pressure-induced disruption of the local environment of Fe-Fe dimers in FeGa₃ accompanied by metallization: *Phys. Rev. B*, 2018, **98**, 020101 https://doi.org/10.1103/PhysRevB.98.020101